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## **REVISION HISTORY**

8/2019—Revision 0: Initial Version

# **SPECIFICATIONS**

## **ELECTRICAL SPECIFICATIONS**

 $V_{DD} = 3.3 \text{ V}, V_{SS} = -2.5 \text{ V}, LS = 3.3 \text{ V}, V_{CTRL} = 0 \text{ V or } 3.3 \text{ V}, and T_{CASE} = 25^{\circ}\text{C in a 50 } \Omega \text{ system, unless otherwise noted.}$ 

Table 1.

Parameter	Symbol	Test Conditions/Comments	Min Typ	Max	Unit
FREQUENCY RANGE	f		100	13,000	MHz
INSERTION LOSS	IL				
Between RFC and RF1 or RFC and RF2 (On)		100 MHz to 3 GHz	0.6		dB
		100 MHz to 8 GHz	0.8		dB
		100 MHz to 10 GHz	1.0		dB
		100 MHz to 13 GHz	1.5		dB
RETURN LOSS	RL				
Between RFC and RF1 or RFC and RF2 (On)		100 MHz to 3 GHz	26		dB
		100 MHz to 8 GHz	22		dB
		100 MHz to 13 GHz	9		dB
RF1 or RF2 (Off)		100 MHz to 3 GHz	26		dB
		100 MHz to 8 GHz	14		dB
		100 MHz to 13 GHz	5		dB
ISOLATION					
Between RFC and RF1 or RCF and RF2 (Off)		100 MHz to 3 GHz	50		dB
		100 MHz to 8 GHz	45		dB
		100 MHz to 10 GHz	35		dB
		100 MHz to 13 GHz	25		dB
SWITCHING CHARACTERISTICS					
Dual Supply		$V_{DD} = 3.3 \text{ V}, V_{SS} = -2.5 \text{ V}$			
Rise Time and Fall Time	t <sub>RISE</sub> , t <sub>FALL</sub>	10% to 90% of RF output	35		ns
On Time and Off Time	ton, toff	50% of triggered digital control input voltage	150		ns
		(V <sub>CTL</sub> ) to 90% of RF output			
RF Settling Time					
0.1 dB		50% of triggered V <sub>CTL</sub> to 0.1 dB of final RF output	300		ns
0.05 dB		50% of triggered V <sub>CTL</sub> to 0.05 dB of final RF output	375		ns
Single Supply		$V_{DD} = 3.3 \text{ V}, V_{SS} = 0 \text{ V}$			
Rise Time and Fall Time	trise, trall	10% to 90% of RF output	180		ns
On Time and Off Time	ton, toff	50% of triggered V <sub>CTL</sub> to 90% of RF output	285		ns
INPUT LINEARITY <sup>1</sup>		100 MHz to 13 GHz			
Dual Supply		$V_{DD} = 3.3 \text{ V}, V_{SS} = -2.5 \text{ V}$			
Input Compression					
0.1 dB	P0.1dB		38		dBm
1 dB	P1dB		39		dBm
Intermodulation Distortion					
Input Third-Order Intercept	IIP3	Two tone input power = 12 dBm each tone, $\Delta f = 1$ MHz	60		dBm
Single Supply		$V_{DD} = 3.3 \text{ V}, V_{SS} = 0 \text{ V}$			
Input Compression					
0.1 dB	P0.1dB		25		dBm
1 dB	P1dB		28		dBm
Intermodulation Distortion					
Input Third-Order Intercept	IIP3	Two tone input power = 12 dBm each tone, $\Delta f = 1$ MHz	55		dBm
SUPPLY CURRENT		V <sub>DD</sub> pin and V <sub>SS</sub> pin			1
Positive Supply Current	I <sub>DD</sub>		20		μΑ
Negative Supply Current	I <sub>SS</sub>		0.5		μA

Parameter	Symbol	Test Conditions/Comments	Min	Тур	Max	Unit
DIGITAL CONTROL INPUTS		V <sub>CTRL</sub> pin and LS pin				
Voltage						
Low	$V_{INL}$		0		0.8	V
High	V <sub>INH</sub>		2		3.3	V
Current						
Low and High Current	I <sub>INL</sub> , I <sub>INH</sub>			<1		μΑ
RECOMMENDED OPERATING CONDITONS						
Supply Voltage						
Positive	$V_{DD}$		3.0		3.6	V
Negative	Vss		-2.75		-2.25	V
Digital Control Input Voltage	$V_{CTL}$		0		$V_{DD}$	V
RF Input Power, Dual Supply <sup>2</sup>	P <sub>IN</sub>	$V_{DD} = 3.3 \text{ V}, V_{SS} = -2.5 \text{ V}, f = 2 \text{ GHz}, T_{CASE} = 85^{\circ}\text{C}^{3}$				
Insertion Loss Path		RF signal is applied to RFC or through connected RF1 or RF2			35	dBm
Isolation Path		RF signal is applied to the terminated RF1 or RF2			27	dBm
Hot Switching		RF signal is present at RFC while switching between RF1 and RF2			27	dBm
RF Input Power, Single Supply <sup>2</sup>	P <sub>IN</sub>	$V_{DD} = 3.3 \text{ V}, V_{SS} = 0 \text{ V}, f = 2 \text{ GHz}, T_{CASE} = 85^{\circ}\text{C}^{3}$				
Insertion Loss Path		RF signal is applied to RFC or through connected RF1 or RF2			27	dBm
Isolation Path		RF signal is applied to the terminated RF1 or RF2			22	dBm
Hot Switching		RF signal is present at RFC while switching between RF1 and RF2			22	dBm
Case Temperature	T <sub>CASE</sub>		-40		+105	°C

<sup>&</sup>lt;sup>1</sup> For input linearity performance vs. frequency, see Figure 13 to Figure 20. <sup>2</sup> For power derating vs. frequency, see Figure 2 and Figure 3. Power derating is applicable for insertion loss path, terminated path, and hot switching power specifications.  $^3$  For operation at 105°C, the power handling degrades from the  $T_{CASE} = 85^{\circ}C$  specification by 3 dB.

## **ABSOLUTE MAXIMUM RATINGS**

#### Table 2.

Table 2.	
Parameter	Rating
Positive Supply Voltage	−0.3 V to +3.7 V
Negative Supply Voltage	−2.8 V to +0.3 V
Digital Control Inputs	
Voltage	$-0.3 \text{ V to V}_{DD} + 0.3 \text{ V}$
Current	3 mA
RF Input Power, Dual Supply <sup>1</sup> ( $V_{DD} = 3.3 \text{ V}$ , $V_{SS} = -2.5 \text{ V}$ , $f = 2 \text{ GHz}$ at $T_{CASE} = 85^{\circ}\text{C}^2$ )	
Insertion Loss Path	37 dBm
Isolation Path	28 dBm
Hot Switching	30 dBm
RF Input Power, Dual Supply <sup>1</sup> ( $V_{DD} = 3.3 \text{ V}$ , $V_{SS} = 0 \text{ V}$ , $f = 2 \text{ GHz at } T_{CASE} = 85^{\circ}\text{C}^{2}$ )	
Insertion Loss Path	28 dBm
Isolation Path	23 dBm
Hot Switching	23 dBm
RF Input Power Under Unbiased Condition ( $V_{DD}$ , $V_{SS} = 0$ V)	23 dBm
Temperature	
Junction, T <sub>J</sub>	135°C
Storage Range	−65°C to +150°C
Reflow	260°C
Electrostatic Discharge (ESD) Sensitivity	
Human Body Model (HBM)	2 kV (Class 2)

<sup>&</sup>lt;sup>1</sup> For power derating vs. frequency, see Figure 2 and Figure 3. Power derating is applicable for insertion loss path, terminated path, and hot switching power specifications.

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

### THERMAL RESISTANCE

Thermal resistance is directly linked to printed circuit board (PCB) design and operating environment. Careful attention to PCB thermal design is required.

 $\theta_{\rm JC}$  is the junction to case bottom (channel to package bottom) thermal resistance.

**Table 3. Thermal Resistance** 

Package Type	θις	Unit
CP-16-38		
Through Path	106	°C/W
Terminated Path	100	°C/W

#### **POWER DERATING CURVES**

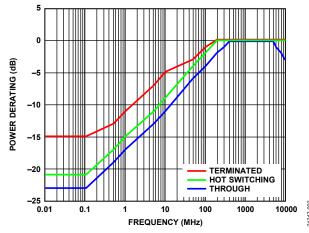


Figure 2. Power Derating vs. Frequency, Low Frequency Detail,  $T_{CASE} = 85^{\circ}C$ 

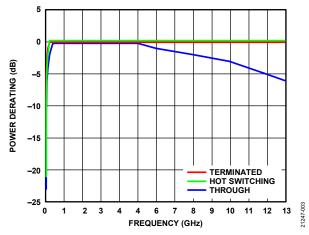


Figure 3. Power Derating vs. Frequency, High Frequency Detail,  $T_{CASE} = 85^{\circ}C$ 

## **ESD CAUTION**



**ESD** (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

 $<sup>^2</sup>$  For operation at 105°C, the power handling degrades from the  $T_{CASE} = 85^{\circ}C$  specification by 3 dB.

## PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

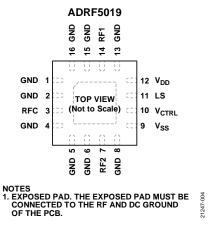


Figure 4. Pin Configuration (Top View)

**Table 4. Pin Function Descriptions** 

Pin No.	Mnemonic	Description			
1, 2, 4 to 6, 8, 13, 15, 16	GND	Ground. These pins must be connected to the RF and dc ground of the PCB.			
3	RFC	F Common Port. This pin is dc-coupled to 0 V and ac matched to 50 $\Omega$ . No dc blocking capacitor is equired when the RF line potential is equal to 0 V dc. See Figure 5 for the interface schematic.			
7	RF2	F Throw Port 2. This pin is dc-coupled to 0 V and ac matched to 50 $\Omega$ . No dc blocking capacitor is equired when the RF line potential is equal to 0 V dc. See Figure 5 for the interface schematic.			
9	Vss	egative Supply Voltage Pin. See Figure 8 for the interface schematic.			
10	V <sub>CTRL</sub>	Control Input Pin. See Figure 6 for interface schematic. See Table 5 for the truth table.			
11	LS	Logic Select Input Pin. See Figure 6 for the interface schematic. See Table 5 for the truth table.			
12	$V_{DD}$	Positive Supply Voltage Pin. See Figure 7 for the interface schematic.			
14	RF1	RF Throw Port 1. This pin is dc-coupled to 0 V and ac matched to 50 $\Omega$ . No dc blocking capacitor is required when the RF line potential is equal to 0 V dc. See Figure 5 for the interface schematic.			
	EPAD	Exposed Pad. The exposed pad must be connected to the RF and dc ground of the PCB.			

## **INTERFACE SCHEMATICS**

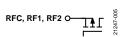


Figure 5. RFC, RF1, and RF2 Pin Interface Schematic

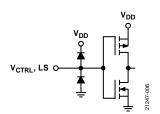


Figure 6. Digital Pins Interface Schematic

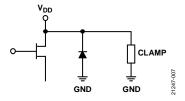


Figure 7. V<sub>DD</sub> Pin Interface Schematic

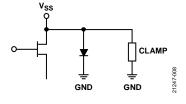


Figure 8. Vss Pin Interface Schematic

# TYPICAL PERFORMANCE CHARACTERICS INSERTION LOSS, RETURN LOSS, AND ISOLATION

 $V_{DD} = 3.3 \text{ V}, V_{SS} = -2.5 \text{ V}, V_{CTRL} \text{ and } LS = 0 \text{ V or } V_{DD}, \text{ and } T_{CASE} = 25^{\circ}\text{C} \text{ in a 50 } \Omega \text{ system, unless otherwise noted.}$ 

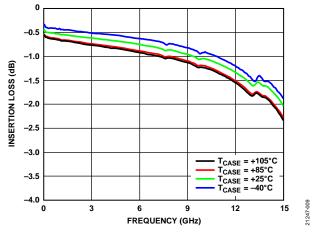


Figure 9. Insertion Loss vs. Frequency over Temperature

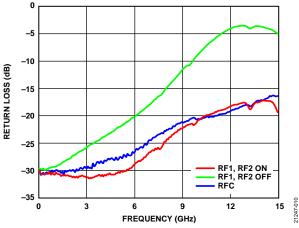


Figure 10. Return Loss vs. Frequency

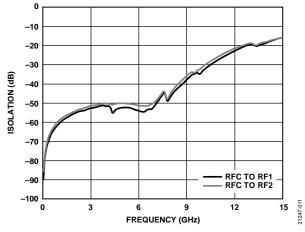


Figure 11. Isolation Between RFC and RFx Ports vs. Frequency

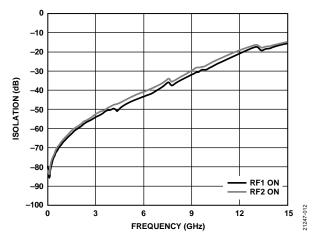


Figure 12. Isolation Between RF1 and RF2 Ports vs. Frequency

## INPUT COMPRESSION AND INPUT THIRD-ORDER INTERCEPT

 $V_{DD}$  = 3.3 V,  $V_{CTRL}$  and LS = 0 V or  $V_{DD}$ , and  $T_{CASE}$  = 25°C in a 50  $\Omega$  system, unless otherwise noted. All of the large signal performance parameters are measured on the ADRF5019-EVALZ evaluation board.

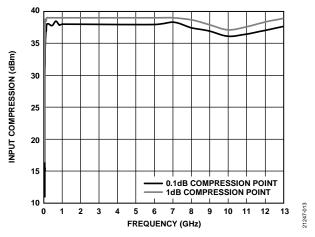


Figure 13. P0.1dB and P1dB Input Compression vs. Frequency,  $V_{SS} = -2.5 V$ 

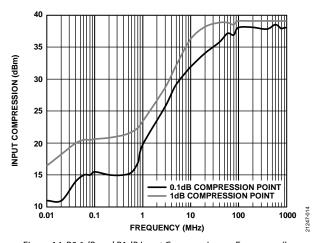


Figure 14. P0.1dB and P1dB Input Compression vs. Frequency (Low Frequency Detail),  $V_{SS} = -2.5 \text{ V}$ 

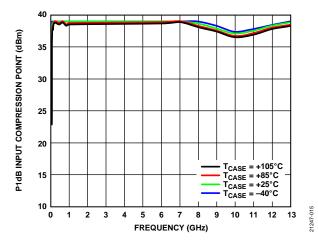


Figure 15. P1dB Input Compression Point vs. Frequency over Temperature,  $V_{SS} = -2.5 V$ 

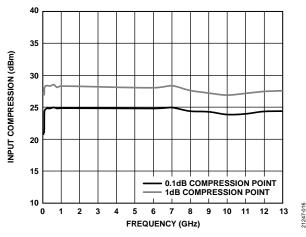


Figure 16. P0.1dB and P1dB Input Compression vs. Frequency,  $V_{SS} = 0 V$ 

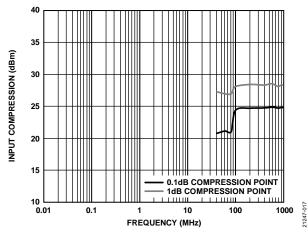


Figure 17. P0.1dB and P1dB Input Compression vs. Frequency (Low Frequency Detail),  $V_{SS} = 0 V$ 

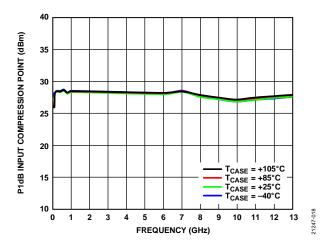


Figure 18. P1dB Input Compression Point vs. Frequency over Temperature (Low Frequency Detail),  $V_{SS} = 0 V$ 

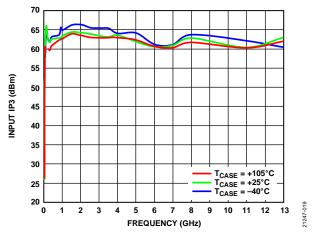


Figure 19. Input IP3 vs. Frequency over Temperature,  $V_{SS} = -2.5 \text{ V}$ 

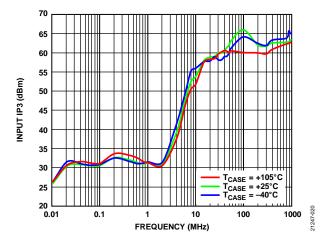


Figure 20. Input IP3 vs. Frequency over Temperature (Low Frequency Detail),  $V_{SS} = -2.5 V$ 

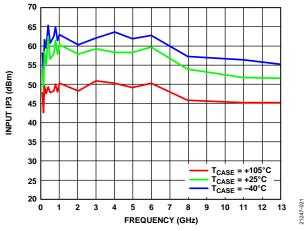


Figure 21. Input IP3 vs. Frequency over Temperature,  $V_{SS} = 0 V$ 

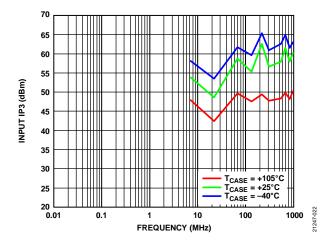


Figure 22. Input IP3 vs. Frequency over Temperature (Low Frequency Detail),  $V_{\rm SS}=0~V$ 

## THEORY OF OPERATION

The ADRF5019 integrates a driver to perform logic functions internally and to provide the user with the advantage of a simplified positive voltage control interface. The driver features two digital control input pins ( $V_{CTRL}$  and LS) that control the state of the RF paths, determining which RF port is in the insertion loss state and which path is in the isolation state (see Table 5).

## **RF INPUT AND OUTPUT**

The RF ports (RFC, RF1, and RF2) are dc-coupled to 0 V, and no dc blocking is required at the RF ports when the RF line potential is equal to 0 V.

The RF ports are internally matched to 50  $\Omega$ . Therefore, external matching networks are not required.

The ADRF5019 is bidirectional with equal power handling capabilities. An RF input signal ( $RF_{IN}$ ) can be applied to the RFC port or to the RF1 port or the RF2 port.

The insertion loss path conducts the RF signal between the selected RF throw port and the RF common port. The isolation path provides high loss between the insertion loss path and the unselected RF throw port, which is nonreflective, by using an internal 50  $\Omega$  termination resistor.

### **POWER SUPPLY**

The ADRF5019 requires a positive supply voltage applied to the  $V_{\text{DD}}$  pin and a negative supply voltage applied to the  $V_{\text{SS}}$  pin. Bypassing capacitors are recommended on the supply lines to filter high frequency noise.

The ideal power-up sequence is as follows:

- 1. Connect to GND.
- 2. Power up the  $V_{DD}$  and  $V_{SS}$  voltages. Power up  $V_{SS}$  after  $V_{DD}$  to avoid current transients on  $V_{DD}$  during ramp up.
- 3. Power up the digital control inputs. The order of the digital control inputs is not important. However, powering the digital control inputs before the  $V_{\rm DD}$  voltage supply can inadvertantly forward bias and damage the internal ESD protection structures. To avoid this damage, use a series  $1~\rm k\Omega$  resistor to limit the current flowing into the control pin. Use pull-up or pull-down resistors if the controller output is in a high impedance state after the  $V_{\rm DD}$  voltage is powered up and the control pins are not driven to a valid logic state.
- Apply an RF input signal to RFC, RF1, or RF2.

The ideal power-down sequence is the reverse order of the power-up sequence.

## **Single-Supply Operation**

The ADRF5019 can operate with a single positive supply voltage applied to the  $V_{\text{DD}}$  pin and  $V_{\text{SS}}$  pin connected to ground. However, some performance degradations can occur in the input compression and input third-order intercept.

**Table 5. Control Voltage Truth Table** 

	Digital Control Inputs		RF Paths		
LS	<b>V</b> <sub>CTRL</sub>	RF1 to RFC	RF2 to RFC		
High	Low	Insertion loss (on)	Isolation (off)		
High	High	Isolation (off)	Insertion loss (on)		
Low	Low	Isolation (off)	Insertion loss (on)		
Low	High	Insertion loss (on)	Isolation (off)		

# APPLICATIONS INFORMATION LAYOUT CONSIDERATIONS

All measurements in this data sheet are measured on the ADRF5019-EVALZ evaluation board. The design of the ADRF5019-EVALZ board serves as a layout recommendation for ADRF5019 application.

See the ADRF5019-EVALZ user guide for more information on using the evaluation board.

## **BOARD LAYOUT**

The ADRF5019-EVALZ is a 4-layer board. The outer copper (Cu) layers are 0.7 mil to 2.2 mil plated and are separated by dielectric materials. Figure 23 shows the ADRF5019-EVALZ board stack up.

The board layout and stackup shown in Figure 23 are used to make the measurements included in this data sheet.

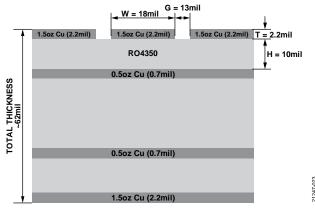


Figure 23. ADRF5019-EVALZ Stack Up

All RF and dc traces are routed on the top copper layer. The inner and bottom layers are ground planes that provide a solid ground for the RF transmission lines. The top dielectric material (H) is 10 mil Rogers RO4350, which allows optimal RF performance. The middle and bottom dielectric layers provide mechanical strength. The overall evaluation board thickness is approximately 62 mil, which allows Subminiature Version A (SMA) connectors to be connected at the board edges.

## **RF AND DIGITAL CONTROLS**

The RF transmission lines use a coplanar waveguide (CPWG) model with a width of 18 mil and a ground spacing (G) of 13 mil and have a characteristic impedance of 50  $\Omega$ . For optimal RF and thermal grounding, as many plated through vias as possible are arranged around the transmission lines and under the exposed pad of the package.

The RF input and output ports (RFC, RF1, and RF2) are connected through 50  $\Omega$  transmission lines to the SMA launchers. On the  $V_{DD}$  and  $V_{SS}$  supply traces, a 100 pF bypass capacitor filters high frequency noise.

Figure 24 shows the simplified application circuit for the ADRF5019.

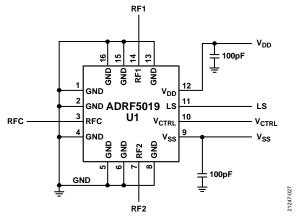


Figure 24. Simplified Application Circuit

## **OUTLINE DIMENSIONS**

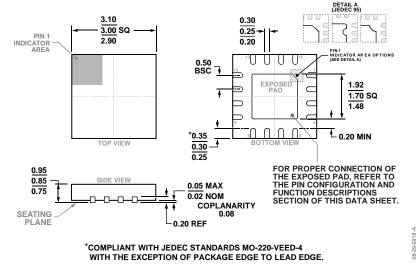


Figure 25. 16-Lead Lead Frame Chip Scale Package [LFCSP] 3 mm × 3 mm Body and 0.85 mm Package Height (CP-16-38)

Dimensions shown in millimeters

## **ORDERING GUIDE**

Model <sup>1</sup>	Temperature Range	Package Description	Package Option	Marking Code
ADRF5019BCPZN	−40°C to +105°C	16-Lead Lead Frame Chip Scale Package [LFCSP]	CP-16-38	S4Z
ADRF5019BCPZN-R7	−40°C to +105°C	16-Lead Lead Frame Chip Scale Package [LFCSP]	CP-16-38	S4Z
ADRF5019-EVALZ		Evaluation Board		

<sup>&</sup>lt;sup>1</sup> Z = RoHS Compliant Part.



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